

Form 1449 (Modified) Information Disclosure Statement By Applicant (Use Several Sheets if Necessary)	Atty Docket No. UNTYP020	Application No.: 10/634,636
	Applicant: Rinerson et al. Filing Date August 4, 2003	Group 2818

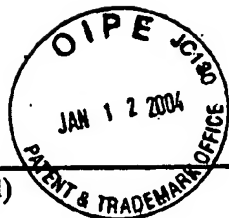
U.S. Patent Documents

Examiner Initial	No.	Patent No.	Date	Patentee	Class	Sub-class	Filing Date
<i>JH</i>	A	6,204,139	2001-03-20	Liu et al.	438	385	

Other Documents

Examiner Initial	No.	Author, Title, Date, Place (e.g. Journal) of Publication
<i>JH</i>	B	Basun, S. A. et al., "Photoinduced Phenomena in $Sr_{1-x}CA_xTiO_2$, $0 \leq x \leq 0.12$ ", Ferroelectrics, Vol. 183, 1996,255-264.
<i>JH</i>	C	Baiatu, T. et al., "dc Electrical Degradation of Perovskite-Type Titanates: III, A Model of the Mechanism", J. Am. Ceram. Soc., Vol. 73, No. 6, 1990,1663-73.
<i>JH</i>	D	Beck, A. et al., "Reproducible switching effect in thin oxide films for memory applications", Applied Physics Letters, Vol. 77, No. 1, 3 July 2000,139-141.
<i>JH</i>	E	Koidl, P. et al., "Photochromism in Ni-doped $SrTiO_3$," Physical Review B, Vol. 14, No. 7, 1 October 1976, 2703-2708.
<i>JH</i>	F	Millis, A. J., "Lattice Effects in Magnetoresistive Manganese Perovskites," Nature, Vol. 392, 12 March 1998, 147-150.
<i>JH</i>	G	Rossel, C. et al., "Electrical current distribution across a metal-insulator-metal structure during bistable switching," Journal of Applied Physics, Vol. 90, No. 6, 15 September 2001, 2892-2898.
<i>JH</i>	H	Simmons, J. G., "New Conduction and Reversible Memory Phenomena in thin insulating films," Proc. Roy. Soc. A., 301, 77-102, 1967.
<i>JH</i>	I	Sze, S.M., "Physics of Semiconductor Devices," Bell Laboratories Inc., Murray Hill, NJ, © 1981 John Wiley & Sons, Inc., ISBN 0-471-05661-8
Examiner	SON MAI	
Date Considered	11-17-04	

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<i>JLC</i>	J	Waser, R., et al., "dc Electrical Degradation of Peroskite-Type Titanates:I, Ceramics", J. Am. Ceram. Soc., Vol. 73, No. 6, 1990,1645-53.
<i>JLC</i>	K	Waser, R., et al., "dc Electrical Degradation of Peroskite-Type Titanates:II, Single Crystals", J. Am. Ceram. Soc., Vol. 73, No. 6, 1990,1654-62.
<i>JLC</i>	L	Waser, R., et al., "Bulk Conductivity and Defect Chemistry of Acceptor-Doped Strontium Titanate in the Quenched State", J. Am. Ceram. Soc., Vol. 74, No. 8, 1991,1934-40.
<i>JLC</i>	M	Watanabe, Y. et al., "Current-driven insulator-conductor transition and nonvolatile memory in chromium-doped SrTiO ₃ single crystals", Applied Physics Letters, Vol. 78, No. 23, 4 June 2001, 3738-3740.
<i>JLC</i>	N	Zimmermann, M.V., et al, "X-Ray Resonant Scattering Studies of Orbital and Charge Ordering in Pr _{1-x} Ca _x MnO ₃ ," Physical Review B., Volume 64, 195133, 1-17.
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